

NEW SCHEME

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First/Second Semester B.E Degree Examination, February/March 2005**Common to All Branches****Basic Electronics**

Time: 3 hrs.]

[Max.Marks : 100]

- Note:** 1. Answer any FIVE full questions.
 2. All questions carry equal marks.
 3. Assume missing data if any suitably.

1. (a) Explain the mechanism of conduction in semiconductors due to electrons & holes. (6 Marks)

(b) Derive an expression for conductivity in a semi-conductor in terms of electron and hole concentrations. (8 Marks)

(c) Estimate the value of resistivity of intrinsic Germanium at $300^{\circ}K$ given :

$$\text{Intrinsic concentration} = 2.5 \times 10^{13} \text{ cm}^{-3}$$

$$\text{Electron mobility} = 3800 \text{ cm}^2 / \text{V} - \text{s}$$

$$\text{Hole mobility} = 1800 \text{ cm}^2 / \text{V} - \text{s}$$

$$\text{Electron charge} = 1.6 \times 10^{-19} \text{ C},$$

(6 Marks)

2. (a) With a neat sketch explain the phenomenon of HALL-EFFECT in semiconductors. (6 Marks)

(b) A germanium diode is used in a rectifier circuit & is operating at a temperature of $25^{\circ}C$ with a reverse saturation current of $1000\mu\text{A}$. Calculate the value of forward current if it is forward biased by 0.22V. Assume the value of $\eta = 1$ for Ge. (8 Marks)

(c) With a neat figures clearly explain the concepts of Zener and avalanche breakdown phenomena. (6 Marks)

3. (a) With a neat sketch, clearly show the various current components in a PNP transistor and hence establish the relevant equations. (10 Marks)

(b) A bridge rectifier is driving a load resistance of 100Ω . It is driven by a source voltage of $230V, 50Hz$. Neglecting diode resistances. Calculate : (6 Marks)

i) Average DC voltage

ii) Average Direct current

iii) frequency of output wave form.

(c) Define α (Alpha) and β (Beta) of a transistor.

(4 Marks)

Contd.... 2

- 4.** (a) Clearly explain the effect of temperature and β on the operating point stability. (8 Marks)

(b) A transistor amplifier is driven by an input voltage of 10mV. The amplifier has a voltage gain of 60dB. Estimate the value of output voltage. (6 Marks)

(c) Explain the need for cascading of amplifier. Write an expression for total voltage gain of a cascaded amplifier. (6 Marks)

- 5.** (a) What is Bark Hausen criterion for oscillations? (6 Marks)

(b) Design the value of an inductor to be used in a Colpitts oscillator to generate a frequency of 10MHz. The circuit is using a value of

$$C_1 = 100\text{pF} \quad \& \quad C_2 = 50\text{pF}. \quad (6 \text{ Marks})$$

(c) Listout the properties of an ideal Opamp and with the circuit symbol explain the significance of inverting & non inverting inputs. (8 Marks)

- 6.** (a) Show with a derivation and circuit diagram, how an opamp can be used as an integrator. (6 Marks)

(b) An opamp is used as an inverting amplifier to amplify an input sine wave of amplitude 100mV(peak to peak). The input resistance $R_i = 1K\Omega$ and feed back resistance $R_f = 10k\Omega$. Calculate the voltage gain and sketch the output wave form to scale. (8 Marks)

(c) Compare the performance of AM & FM communication systems. (6 Marks)

- 7.** (a) Derive an expression for the instantaneous value of an AM signal in terms of carrier and side band frequencies. (8 Marks)

(b) Carryout the following conversion

- $(F9AC \cdot 5D8B)_{16} = (?)_{10}$
- $(457 \cdot 245)_8 = (?)_{10}$

(6 Marks)

(c) Carryout subtraction using :

- 1's complement for $(101101 - 11001)_2$
- 2's complement for $(11001 - 101101)_2$.

(6 Marks)

- 8.** (a) Explain the operation of a two input TTL NAND gate using a neat circuit diagram. (8 Marks)

(b) With truth table explain how a $R-S$ flip flop can be realised using NOR gates. (6 Marks)

(c) Show how amplitude, frequency and phase can be measured using a CRO. (6 Marks)
